

Changehun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

**EO-355-Subnano-Hi**/1~600μJ/1~3W

## **HIGH ENERGY DIODE PUMPED ALL-SOLID-STATE Q-SWITCHED LASER**

High energy diode pumped all solid state Q-switched laser at 355nm has the features of high single pulse energy, short pulse duration, and high peak power, which is widely used in scientific research, film stripping, LIF, Tissue ablation and so on.









## SPECIFICATIONS

Wavelength (nm)	355±1nm	355±1nm  Q-switched: EO (Electro-optic)	
Operating mode	Q-switched: EO (Electro-optic)		
Single pulse energy (uJ)	300uJ@5KHz	600uJ@5KHz	
Output power (W)	1.5	3	
Power stability	<5%		
Pulse duration (ns)	<1.5ns@5KHz	~1.5ns@5KHz	
Rep. rate (kHz)	100Hz~10kHz (Customized)		
Beam diameter (mm)	~1.5mm		
Beam divergence, full angle (mrad)	≤3mrad		
Cooled method	Air cooled@<2kHz; Water cooled@>2kHz		
Warm-up time (minutes)	<15		
Power supply	DC 24V		
Operating temperature (°C)	15~30		
Expected lifetime (hours)	10000h		
Warranty period	l year		





